

# 30A 60V LOW VF SchottkyBarrierDiode

## 1 Description

Dual center tab Schottky rectifier suited for High Frequency server and telecom base station SMPS. Packaged in TO Inside the package, this device combineshigh current rating and low volume to enhance both reliability and power density of the application.

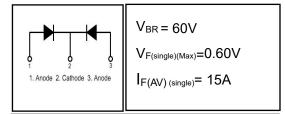
TO-220F provides insulation voltage rated at 2000V RMS from all three terminals to external heatsink.

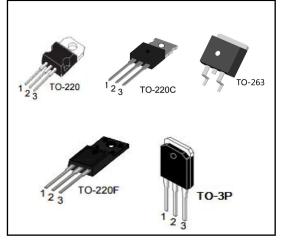
#### 2 Features

- High junction temperature capabiliy
- Low leakage current
- Low thermal resistance
- High frequency operation
- Avalanche specification

## 3 Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose





#### 4 Electrical Characteristics

## **4.1 Absolute Maximum Ratings** (Tc=25 °C,unless otherwise noted)

PARAMETER			SYMBOL	VALUE	UNIT
Peak Repetitive Reverse Voltage			V <sub>RRM</sub>	60	V
RMS Reverse Voltage			V <sub>R(RMS)</sub>	42	V
DC Blocking Voltage			V <sub>R</sub>	60	V
Average Rectified Forward Current(single)	TO-220F,Tc=90° <sub>C</sub> TO-220/263/3P,Tc=120° <sub>C</sub>			15	Α
Average Rectified Forward Current(double)			I <sub>F(AV)</sub>	30	Α
Repetitive Peak Surge Current(single)	Repetitive Peak Surge Current(single)			25	Α
Nonrepetitive Peak Surge Current(single)	t	t=8.3ms	I <sub>FSM</sub>	250	Α
Reverse Surge Current (Note 1)			I <sub>RSM</sub>	8	Α
Operating Junction Temperature Range			Tj	<b>-</b> 55∼150	$^{\circ}$
Storage Temperature Range			T <sub>stg</sub>	<b>-</b> 55∼150	${\mathbb C}$
ESD (Machine Model=C)				>400	V
ESD (Human Body Model=3B)				>8000	V
ESD(Noncontact)				>15000	V

#### 4.2 Thermal Characteristics

PARAMETER	SYMBOL	VALUE				UNIT
FARAWETER		To-3P	TO-220	TO-263	TO-220F	ONIT
Thermal Resistance, Junction to Case-sink	R <sub>thJC</sub>	0.65	1.0	0.90	2.0	°C/W



#### 4.3 Electrical Characteristics

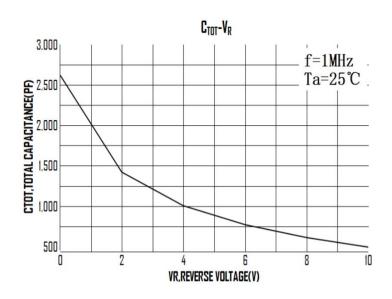
(Tc=25<sup>°</sup>C,unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Maximum Instantaneous	V <sub>F</sub>	I <sub>F</sub> = 10A	-	0.48	-	V
Forward Voltage(Note 3)		I <sub>F</sub> = 15A	-	0.54	0.60	V
		I <sub>F</sub> = 15A, T <sub>C</sub> = 125°C	-	-	0.55	V
		I <sub>F</sub> = 30A	-	0.70	-	V
Maximum Instantaneous	I <sub>R</sub>	V <sub>R</sub> = 60V	-	25	100	uA
Reverse (Note 2)		V <sub>R</sub> = 60V, T <sub>C</sub> = 125°C	-	-	30	mA
Total capacitance	Ctot	V <sub>R</sub> =10V f=1MHz	-	520	-	pF
DC Blocking Voltage	V <sub>BR</sub>	I <sub>R</sub> =100uA	60	72	-	V

#### Notes

- 1. 2.0us Pulse Width, f=1.0 KHz
- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. VF Instantaneous forward voltage (pw =  $300\mu s$ , D = 2%).

# 5 Typical characteristics diagrams



Ta=125°C

Ta=100°C

Ta=75°C

Ta=25°C

Ta=25°C

Ta=25°C

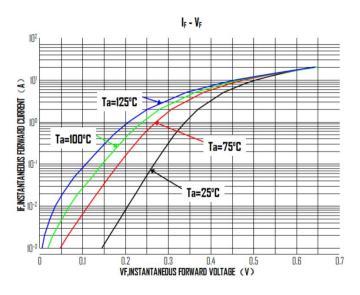
Ta=25°C

VR.INSTANTANEOUS REVERSE VOLTAGE (V)

IR - VR

FIGURE 1. Total capacitance vs Voltage

FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE



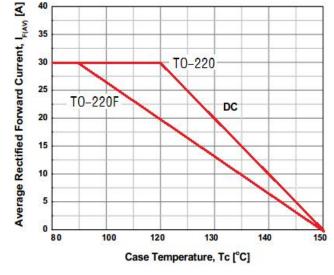


FIGURE 3. FORWARD CURRENT vs FORWARD VOLTAGE

FIGURE 4. CURRENT DERATING CURVE

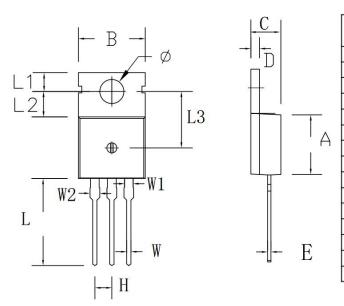


# **Product Specifications and Packaging Models**

Product Model	Package Type	Mark Name	RoHS	Package	Quantity
MBR30R60CTS	TO-263	MBR30R60CTS	Pb-free	Braid	800/disc
MBR30R60CTS	TO-220	MBR30R60CTS	Pb-free	Tube	1000/box
MBR30R60DCTS	TO-3P	MBR30R60DCTS	Pb-free	Tube	300/box
MBRF30R60CTS	TO-220F	MBRF30R60CTS	Pb-free	Tube	1000/box

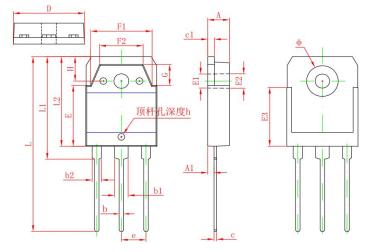
## **Dimensions**

# TO-220C PACKAGE OUTLINE DIMENSIONS



Camb a 1	Dimensions In	Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	8. 80	9. 30	0.346	0.366
В	9. 70	10.30	0. 382	0.406
С	4. 25	4. 75	0. 167	0. 187
D	1. 20	1.45	0.047	0.057
Е	0. 40	0.60	0.016	0.024
Н	2. 54	2. 54 TYP		TYP
W	0.60	0.95	0.024	0.037
W1	1. 05	1.45	0.041	0.057
W2	1. 20	1.60	0.047	0.063
L	12.60	13. 40	0. 496	0. 528
L1	2. 45	2. 95	0.096	0. 116
L2	3. 45	3. 95	0. 136	0. 156
L3	8. 15	8. 65	0. 321	0. 341
Φ	3. 50	3. 90	0. 138	0. 154

## TO-3P PACKAGE OUTLINE DIMENSIONS



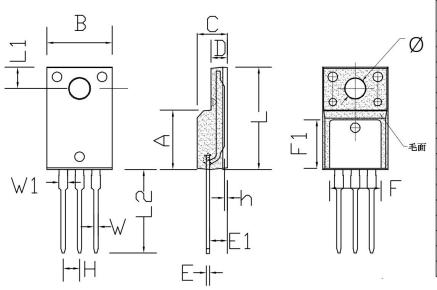
C	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	M in	Max	Min	Max	
Α	4.600	5.000	0.181	0.197	
A 1	1.200	1.600	0.047	0.063	
b	0.800	1.200	0.031	0.047	
b 1	2.800	3.200	0.110	0.126	
b 2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.450	1.650	0.057	0.065	
D	15.450	15.850	0.608	0.624	
E	13.700	14.100	0.539	0.555	
E 1	3.200 REF		0.126 REF		
E 2	3.300 REF		0.130 REF		
E 3	13.450	REF	0.530 REF		
F 1	13.400	13.800	0.528	0.543	
F2	9.400	9.800	0.370	0.386	
L	39.900	40.300	1.571	1.587	
L1	23.200	23.600	0.913	0.929	
L2	20.300	20.600	0.799	0.811	
Φ	6.900	7.100	0.272	0.280	
G	5.150	5.550	0.203	0.219	
е	5.450	TYP	0.215 TYP		
Н	5.000	REF	0.197	REF	
h	0.000	0.300	0.000	0.012	

Dimensions In Millimeters

Dimensions In Inches

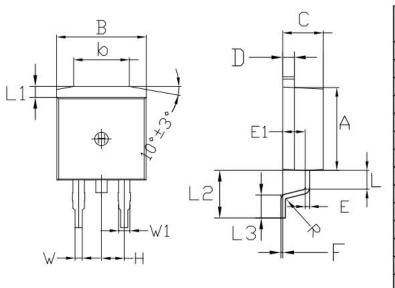


# TO-220F PACKAGE OUTLINE DIMENSIONS



6 1 1	DimensionsIn	Millimeters	DimensionsIn Inches		
Symbol	min.	max.	min.	max.	
Α	8.80	9.30	0.346	0.366	
В	10.00	10.50	0.394	0.413	
С	4.30	4.90	0.169	0.193	
D	2.30	2.70	0.091	0.106	
L	15.55	16.15	0.612	0.636	
h	0.40	0.60	0.016	0.024	
L1	3.15	3.55	0.124	0.140	
L2	12.65	13.35	0.498	0.526	
W	0.70	0.90	0.028	0.035	
W1	1.15	1.55	0.045	0.061	
Н	2.54	TYP	0.100	TYP	
E	0.48	0.53	0.019	0.021	
ф	2.90	3.40	0.114	0.134	
E1	2.40	2.90	0.094	0.114	
F	7.75	8.25	0.305	0.325	
F1	7 35	7.85	0.289	0.309	

# TO-263 PACKAGE OUTLINE DIMENSIONS



C 1 1	Dimensions I	n Millimeters	Dimensions	In Inches
Symbol	min.	max.	min.	max.
A	8. 80	9.30	0. 346	0. 366
В	9. 70	10. 30	0. 382	0. 406
C	4. 25	4. 75	0. 167	0. 187
D	1.20	1.45	0. 047	0.057
Е	0. 40	0.60	0.016	0. 024
L	12. 25	13. 75	0. 482	0. 541
L1	1.15	1. 45	0.045	0.057
R	0. 24	0. 26	0.0095	0. 0102
W	0.80	0.82	0.0315	0. 0323
W1	1.20	1. 30	0. 047	0.051
Н	2. 5	54 TYP	0. 200	TYP
b	5. 50	6. 50	0. 216	0. 256
E1	2. 4	2. 6	0.0946	0. 1024
L2	5. 20	5. 80	0. 205	0. 228
L3	2. 20	3. 20	0.087	0. 126
F	0. 03	0. 23	0.0012	0.0091



#### 8 Attentions

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- Product promotion is endless, our company will be dedicated to provide customers with better products.

# 9 Appendix

## Revision history:

Date	REV.	Description	Page
2020.4.19	1.0	Original	